

LOSS OF ENERGY OF MICROWAVE PROPAGATING THROUGH MICROSTRIPLINE STRUCTURE

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ABSTRACT

Microwave Integrated circuits (MIC'S) have changed since the days of large scale waveguides and co-axial component arrays to small light weight assemblies with introduction of microwave striplines, microslotlines, coplanar strip lines and coplanar waveguide etc. There are different transmission structures used for sending the message information, ideas and power (energy) from one place to another how far remote it is. The two parallel wire transmission line structure, coaxial line, & wave guide have become absolute now- a- days due to their bulky size, heavy cost and power loss in gigahertz range of frequency. The planar transmission line (2-dimensional) technology has been developed due to advent of microwave integrated circuits (MIC's) owing to certain special features and characteristics such as: Miniaturized size, Reduced weight, Low cost, & Minimum power consumption. The present work aims at the study of characteristics impedance, phase velocity, Guide wavelength, consequent Rise of Temperature due to energy loss of microwave propagating through single microstrip structure. It is necessary to study these characteristics parameters to study different type of losses occurred during the propagation of electromagnetic waves through these structures. The TEM mode of propagation of wave is considered in the lower GHz range of frequency. This study also helps in the study of variation losses due to stripwidth and permittivity of substrate used in the microstripline structure.

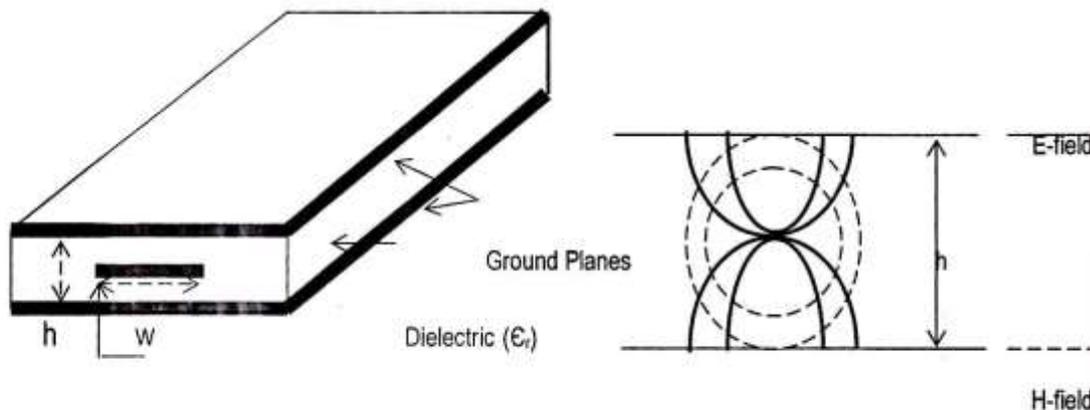
KEYWORDS: Substrate, Permittivity, Microstripline.

INTRODUCTION

The field of microwave is found very important in many new and exciting applications in last four decades. Microwave is a primary vehicle for information exchange which makes greater importance in the international relation and global understanding. The great interest in microwave frequency arises from 10⁹ to 10¹² Hz. This microwave spectrum accommodates many more communication channels which becomes common in society. With increasing need of microwave frequency it becomes necessary to develop different forms of planar transmission structure having properties: less lossy, reduced in weight and volume, reduced cost in mass production, and more reliable.

There are different systems for transmission of microwave signals. The simplest one is the two parallel wire transmission lines which is one dimensional structure and too much lossy in microwave frequency range. This leads to the idea of development of other transmission structure such as waveguide which is a three dimensional structure used for TE-mode/Tm-mode. This is too lossy in giga hertz frequency range.

Stripline and microstriplines devices are the convenient substitute for the bulky structure. The stripline structure is a three conductor TEM-mode transmission line. It consists of a thin conductor strip sandwiched between two dielectric laminates metalized on the outer sides (fig 1.a). the field configuration is shown in fig (1.b) which shows that the field line concentrate around the strip conductor and decrease outward with distance away from the metal strip. It is an excellent medium for realizing passive components but it suffers from the conductor and dielectric loss. These loss are studied by introducing microstriplines structure.



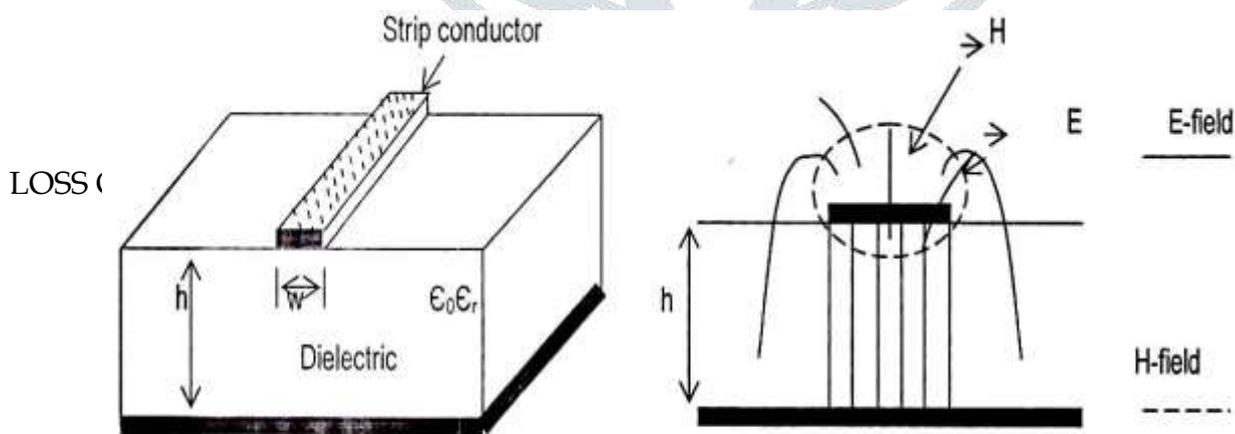
Strip conductor
Fig 1a Stripline (TEM-Mode)

Fig 1b Stripline field configurations

CONCEPT OF MICROSTRIPLINE STRUCTURE

It is a simplest and modified form of stripline. The microstripes structure consists of a narrow conductor strip on one side of a dielectric substrate other side of which is metalized to serve as a ground plane shown in fig (2 a). The electric field lines and magnetic field configuration is shown in fig(2 b)

It is an open structure and simple in realization. The field lines are confined in the vicinity of the strip conductor with a large concentration inside substrate and smaller in the air region it depends on the permittivity of the substrate used, Suitable substrate is preferred which can minimize the dielectric loss



Ground plane
Fig 2. a Microstripline (Quasi-TEM Mode)

Fig 2.b Microstrip Field configuration

conductor on the surface effective permittivity ϵ_{reff} is considered for the calculation of the characteristics and its losses. The knowledge of characteristic impedance and phase velocity

enable us to obtain the energy losses of the wave travelling through the structure. The characteristics impedance is given by 2

$$Z = \frac{1}{v_{p.c}} \dots\dots\dots 1$$

$$= Z_0/\sqrt{\epsilon_{reff}}. \dots\dots\dots 2$$

Guide wavelength of the wave inside the structure is given by

$$\lambda_g = \lambda_0/\sqrt{\epsilon_{reff}}. \dots\dots\dots 3$$

Phase velocity of the wave travelling through the structure is given as

$$V_p = C/\sqrt{\epsilon_{reff}}.$$

Where, c = velocity of the wave in free space and $\sqrt{\epsilon_{reff}}$ = effective permittivity of the inside the structure .

The value of ϵ_{reff} lies in the range $0.5(1+\epsilon_r) \leq \epsilon_{reff} \leq \epsilon_r$ depending on the value of strip width (w) and substrate height (h). For small $w/h \ll 1$, the electric field lines are distributed nearly equally between the substrate and air region and ϵ_{reff} approaches the lower limits $(\epsilon_r + 1)/2$. For wide strip ($w/h \gg 1$), the electric field lines are concentrated mostly between the strip conductor and the ground plane. This configuration makes the microstrip line to be resembled with a parallel plate capacitor with ϵ_{reff} . Approaching ϵ_r .

ENERGY LOSS OF MICROWAVE TRAVELLING THROUGH THE MICROSTRIPLINE STRUCTURE

The stripline and microstripline though are less lossy, they suffers most from Dielectric loss and Conductor loss (Skin loss). The dielectric loss is due to finite loss tangent of the dielectric substrate and conductor loss is due to the finite resistivity of the strip conductor. The loss tangent is expressed as

$$\text{Tan } \delta = \sigma/w\epsilon_r$$

Where, σ = specific conductivity of the substrate and ϵ_r = permittivity of the substrate.

$$W = 2\pi f = \text{the operating angular frequency.}$$

These energy losses have been studied by several investigators. If a_c be denoted as the attenuation constant due to the conductor loss and a_d as the attenuation constant due to dielectric loss, both expressed in dB/ unit length, then total attenuation is given as

$$a = a_c + a_d \text{ dB/unit length}$$

Where

$$a_d = 27.3 \left(\frac{\tan\sigma}{\lambda_0}\right) \{\epsilon_r/\sqrt{\epsilon_{eff}} (\epsilon_{eff}-1)/ \epsilon_{r-1}\} \dots\dots\dots 5$$

Where, λ_0 = free space wavelength, ϵ_r = the equivalent relative permittivity,

And

$$a_c = 8.68 R_s / Z_0 W$$

Where R_s = Surface resistivity = $\sqrt{\mu\pi f}/\sigma_c$, σ_c = conductivity of the metal strip.

$$\mu = \text{Permeability of the medium and } f = \text{Operating frequency.}$$

Total Energy loss = Joule Energy Loss + Dielectric Energy Loss. This causes rise of temperature expressed by

$$\sigma T = \left(\frac{0.23h}{K}\right) \left\{\frac{a_c}{w}\right\} + \left(\frac{a_d}{2w}\right) \text{ } ^\circ\text{C/watt} \dots\dots\dots 7$$

This is calculated for different metal strip width, different height of the substrate using different permittivity.

After exhaustive computation the energy loss in terms of rise temperature for different stripwidth and different relative permittivity have been studied and the results are placed in table- 1 assuming $f = \text{frequency} = 3 \text{ GHz}$, $t = 0.01 \text{ mils}$ and $h = 100 \text{ mils}$.

Stripwidth h (w) mils	$\epsilon_r = 3.25(\text{Fused Quartz})$		$\epsilon_r = 6(\text{Berila})$			$\epsilon_r = 10(\text{Alumina})$			
	ϵ_{reff}	$Z_0(\Omega)$	ΔT ($^{\circ}\text{C}$)	ϵ_{reff}	$Z_0(\Omega)$	ΔT ($^{\circ}\text{C}$)	ϵ_{reff}	$Z_0(\Omega)$	ΔT ($^{\circ}\text{C}$)
10	2.70	166.25	30.70	3.25	141.50	36.75	5.85	1.16.15	42.25
50	2.80	103.70	10.20	3.70	93.85	11.60	6.30	62.25	15.50
100	2.85	76.92	6.50	3.85	61.35	7.65	6.52	57.80	10.55
150	2.90	64.15	5.25	4.00	51.22	6.50	6.75	37.92	7.35
200	2.95	55.20	4.65	4.25	41.32	6.25	6.95	32.45	6.85

Table 1 variation of energy loss with stripwidth & permittivity

DISCUSSION AND CONCLUSION

From the table it has been found that energy loss due to propagation of microwave through microstripline depends due to presence of metal strip and dielectric material of different nature. The increase of stripwidth decreases the energy loss and consequent rise in temperature. Further this energy loss is larger for dielectric materials of higher permittivity. Discussion of the result exhibits that change of strip geometry causes the distortion of field and flow of power through the stripline gets affected. In case of narrower strip, energy loss is large. Thus it can be concluded that to get smaller energy loss relatively wider metal strip and substrate material of lower relative permittivity should be taken for the design of any device based on planer strip like patch antenna, isolator, resonator and couplers.

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